Ordering number: EN5906

N-Channel Silicon MOSFET



FTS2002

DC-DC Converter Applications

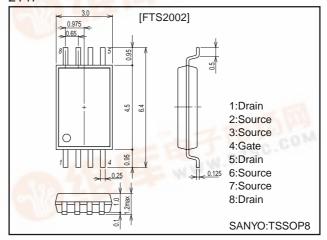
Features

- · Low ON resistance.
- · 4V dirve.
- · Mount height 1.1mm.

Package Dimensions

unit:mm

2147



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		30	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	ID	110	5	Α
Drain Current (pulse)	I _{DP}	PW≤10µs, duty cycle≤1%	30	Α
Allowable Power Dissipation	P _D	Mounted on a ceramic board (1000mm ² ×0.8mm)	1.5	W
Channel Temperature	Tch	A 7 Lb	150	°C
Storage Temperature	Tstg	6//6	-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
Farameter		Conditions		typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0	30			V
Zero-Gate Votlage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0			100	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0			±10	μΑ
Gate-to-Source Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.0	_	2.5	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =5A	8	10	7 7 7 7	S
Static Drain-to-Source On-State Resistance	R _{DS(on)} 1	I _D =5A, V _{GS} =10V		24	32	mΩ
	R _{DS(on)} 2	I _D =3A, V _{GS} =4V	WW.	37	50	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz	-	700		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		380		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		180		pF

Continued on next page.

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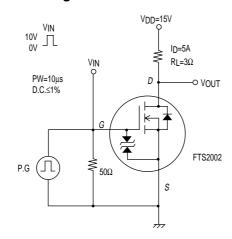
SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquaters
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

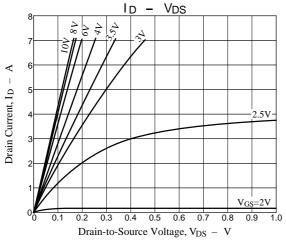
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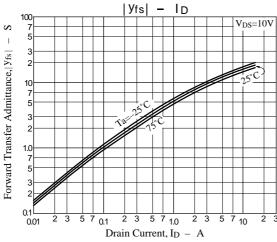
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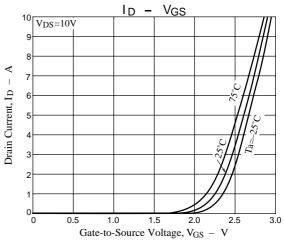
Parameter	Symbol	Conditions	Ratings			Unit
Turn-ON Delay Time	td(on)	See specified Test Circuit		15		ns
Rise Time	t _r	See specified Test Circuit		180		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		90		ns
Fall Time	t _f	See specified Test Circuit		80		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =5A		22		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =5A		5		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =5A		6		nC
Diode Forward Voltage	V _{SD}	I _S =5A, V _{GS} =0		1.0	1.2	V

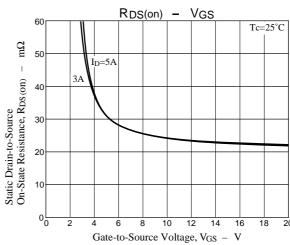
Switching Time Test Circuit



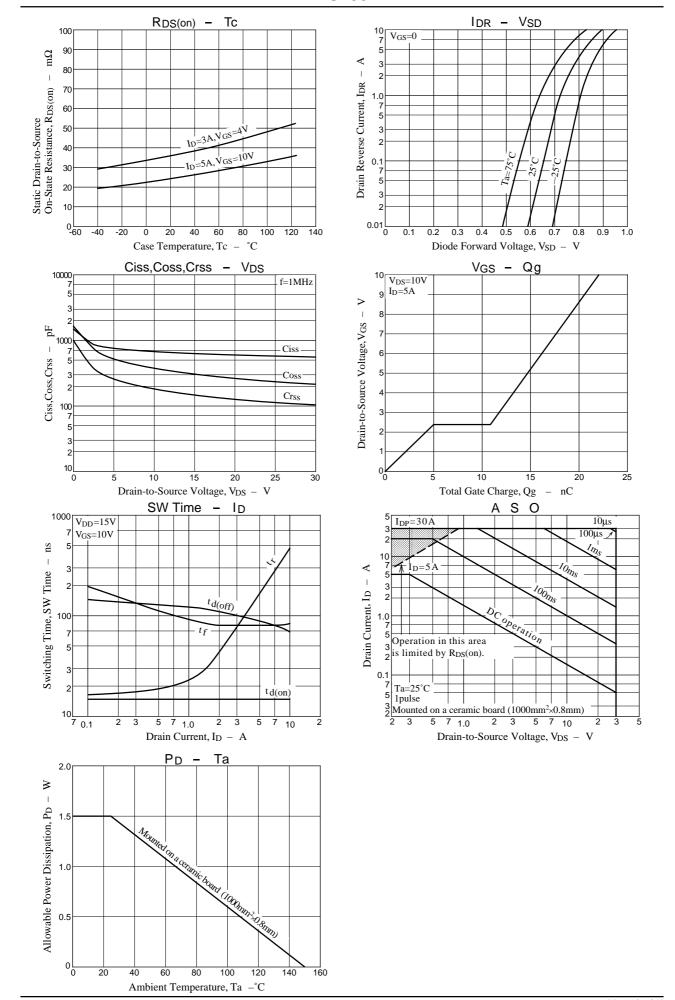








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